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UTILITY PATENT APPLICATION TRANSMITTAL

Attorney Docket No. NC No. 82,745

First Inventor or Application Identifier Chrisey et al

Title MATRIX ASSISTED PULSED LASER EVAPORATION DIRECT WRITE

Express Mail Label No.

(Only for new nonprovisional applications under 37 C.F.R. § 1.53(b)) Assistant Commissioner for Patents APPLICATION ELEMENTS ADDRESS TO: **Box Patent Application** See MPEP chapter 600 concerning utility patent application contents. Washington, DC 20231 Fee Transmittal Form (e.g., PTO/SB/17) 5. Microfiche Computer Program (Appendix) (Submit an original and a duplicate for fee processing) 6. Nucleotide and/or Amino Acid Sequence Submission 2. Specification [Total Pages 36 (if applicable, all necessary) (preferred arrangement set forth below) - Descriptive title of the Invention Computer Readable Copy - Cross References to Related Applications b. Paper Copy (identical to computer copy) - Statement Regarding Fed sponsored R & D Statement verifying identity of above copies - Reference to Microfiche Appendix c. - Background of the Invention **ACCOMPANYING APPLICATION PARTS** - Brief Summary of the Invention Assignment Papers (cover sheet & document(s)) - Brief Description of the Drawings (if filed) 37 C.F.R.§3.73(b) Statement (Power of - Detailed Description 8. (when there is an assignee) - Claim(s) 9. English Translation Document (if applicable) - Abstract of the Disclosure Information Disclosure Copies of IDS Drawing(s) (35 U.S.C. 113) [Total Sheets Statement (IDS)/PTO-1449 Citations 4. Oath or Declaration Preliminary Amendment [Total Pages 37 Return Receipt Postcard (MPEP 503) Newly executed (original or copy) 12. (Should be specifically itemized) Copy from a prior application (37 C.F.R. § 1.63(d)) * Small Entity (for continuation/divisional with Box 16 completed) Statement filed in prior application, 13. Statement(s) Status still proper and desired **DELETION OF INVENTOR(S)** (PTO/SB/09-12) Signed statement attached deleting Certified Copy of Priority Document(s) inventor(s) named in the prior application, (if foreign priority is claimed) see 37 C.F.R. §§ 1.63(d)(2) and 1.33(b). Other: NOTE FOR ITEMS 1 & 13: IN ORDER TO BE ENTITLED TO PAY SMALL ENTIT FEES, A SMALL ENTITY STATEMENT IS REQUIRED (37 C.F.R. § 1.27), EXCEPT IF ONE FILED IN A PRIOR APPLICATION IS RELIED UPON (37 C.F.R. § 1.28). 16. If a CONTINUING APPLICATION, check appropriate box, and supply the requisite information below and in a preliminary amendment: Continuation Divisional of prior application No: 09 Continuation-in-part (CIP) ,318,134 Group / Art Unit: 1762 Prior application information. Examiner M Padgett For CONTINUATION or DIVISIONAL APPS only: The entire disclosure of the prior application, from which an oath or declaration is supplied under Box 4b, is considered a part of the disclosure of the accompanying continuation or divisional application and is hereby incorporated by reference. The incorporation can only be relied upon when a portion has been inadvertently omitted from the submitted application parts. 17. CORRESPONDENCE ADDRESS Customer Number or Bar Code Label Correspondence address below (Insert Customer No. or Attach bar code label here) Philip E. Ketner Name Code 1008.2, Naval Research Laboratory Address 4555 Overlook Ave., S.W. City Washington D.C State 20375-5320 Zip Code USA Country Telephone Fax 202-404-7380 Name (Pnnt/Type) John J. Karasek Registration No. (Attomey/Agent) 36,182 Sionature Date

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FEE TRANSMITTA

for FY 2000

Patent fees are subject to annual revision. Small Entity payments must be supported by a small entity statement, otherwise large entity fees must be paid. See Forms PTO/SB/09-12. See 37 C.F.R. §§ 1.27 and 1.28.

TOTAL AMOUNT OF PAYMENT

WARNING!

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Complete if Known			
Application Number			
Filing Date	May 25, 1999		
First Named Inventor	Chrisey et al		
Examiner Name	M. Padgett		
Group / Art Unit	1762		
Attorney Docket No.	NC No. 82,745		

METHOD OF PAYMENT (check one)	FEE CALCULATION (continued)				
1. X The Commissioner is hereby authorized to charge indicated fees and credit any overnaments to	3. ADDITIONAL FEES				
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FEE CALCULATION	115 110 215 55 Extension for reply within first month				
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BASIC FILING FEE Large Entity Small Entity	117 870 217 435 Extension for reply within third month				
Fee Fee Fee Fee Description	118 1,360 218 680 Extension for reply within fourth month				
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107 480 207 240 Plant filing fee	120 300 220 150 Filing a brief in support of an appeal				
108 690 208 345 Reissue filing fee	121 260 221 130 Request for oral hearing				
114 150 214 75 Provisional filing fee	138 1,510 138 1,510 Petition to institute a public use proceeding				
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SUBMITTED BY	Complete (if applicable)	$\overline{}$			
Name (PnntlType) Barry A. Edelberg	Registration No. (Attorney/Agent) 31,012 Telephone (202)404-1551				
Signature	- KAR - Date 9/07/57)				

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Chrisey, et al Application No.: To be assigned (Divisional of Appln. No. 09/318,134)

Filed: On even date herewith

For: MATRIX ASSISTED PULSED LASER EVAPORATION DIRECT

WRITE

Examiner: To be assigned Group Art Unit: To be assigned

September 26, 2000

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Prior to an examination on the merits, please amend the above-identified application as follows:

IN THE SPECIFICATION:

Page 1, after the title of the invention, insert the following new paragraph:

--This is a divisional application of copending Application No. 09/318,134, filed May 25, 1999. Application No. 09/318,134 is hereby incorporated herein by reference.--

IN THE CLAIMS:

Please cancel claims 20 through 37.

Application No.: To be assigned (Divisional of Appln. No. 09/318,134)

Applicant(s): Chrisey, et al

PATENT APPLICATION

Docket No.: N.C. 82,745

REMARKS

This application has been revised to place it in better condition for examination. Upon entry of this preliminary amendment, only claims 1 through 19 will appear in this case.

A favorable action at the Examiner's earliest convenience is earnestly solicited.

Kindly charge any additional fees due, or credit overpayment of fees, to Deposit Account No. 50-0281.

Prepared by: Philip Edward Ketner Reg. No. 46,272

(202)404-1554

Respectfully submitted,

John J. Karasek Reg. No. 36,182 September 27, 2000



DEPARTMENT OF THE NAVY

NAVAL RESEARCH LABORATORY 4555 OVERLOOK AVE SW WASHINGTON D C 20375-5320

IN REPLY REFER TO:

Navy Case No. 79,702

APPLICATION FOR LETTERS PATENT

TO ALL WHOM IT MAY CONCERN:

Alberto Pique are citizens of the United States of America, and residents of Bowie, MD, Lorton, VA, and Bowie, MD have invented certain new and useful improvements in "MATRIX ASSISTED PULSED LASER EVAPORATION DIRECT WRITE" of which the following is a specification:

Prepared by:
Ralph T. Webb
Reg. No. 33047
Tele. No. (202) 404-1554

Inventor's Name: Douglas B. Chrisey, R. Andrew McGill and Alberto Pique

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MATRIX ASSISTED PULSED LASER EVAPORATION DIRECT WRITE

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Background of the Invention

1. Field of the Invention

The invention relates generally to the deposition of materials and more specifically to devices, materials and methods for direct writing of a wide range of different materials onto substrates.

2. Description of the Related Art

The term "direct write" refers generally to any technique for creating a pattern directly on a substrate, either by adding or removing material from the substrate, without the use of a mask or preexisting form. Direct write technologies have been developed in response to a need in the electronics industry for a means to rapidly prototype passive circuit elements on various substrates. especially in the mesoscopic regime, that is, electronic devices that straddle the size range between conventional microelectronics (sub-micron-range) and traditional surface mount components (10+ mm-range). (Direct writing may also be accomplished in the sub-micron range using electron beams or focused ion beams, but these techniques, because of their small scale, are not appropriate for large scale rapid prototyping.) Direct writing allows for circuits to be prototyped without iterations in photolithographic mask design and allows the rapid evaluation of the performance of circuits too

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difficult to accurately model. Further, direct writing allows for the size of printed circuit boards and other structures to be reduced by allowing passive circuit elements to be conformably incorporated into the structure. Direct writing can be controlled with CAD/CAM programs, thereby allowing electronic circuits to be fabricated by machinery operated by unskilled personnel or allowing designers to move quickly from a design to a working prototype. Mesoscopic direct write technologies have the potential to enable new capabilities to produce next generation applications in the mesoscopic regime. Other applications of direct write technologies in microelectronic fabrication include forming ohmic contacts, forming interconnects for circuit and photolithographic mask repair, device restructuring and customization, design and fault correction.

Currently known direct write technologies for adding materials to a substrate include ink jet printing, Micropen^c, laser chemical vapor deposition (LCVD) and laser engineered nano-shaping (LENS). Currently known direct write technologies for removing material from a substrate include laser machining, laser trimming and laser drilling.

The direct writing techniques of ink jet printing, screening and Micropen® are wet techniques, that is, the material to be deposited is combined with a solvent or binder and is squirted onto a substrate. The solvent or binder must later be removed by a drying or curing process, which limits the flexibility and capability of these approaches. In addition, wet techniques are inherently limited by viscoelastic properties of the fluid in which the particles are suspended or dissolved.

In the direct writing technique known as "laser induced forward transfer" (LIFT), a pulsed laser beam is directed through a laser-transparent target substrate to strike a film of material coated

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on the opposite side of the target substrate. The laser vaporizes the film material as it absorbs the laser radiation and, due to the transfer of momentum, the material is removed from the target substrate and is redeposited on a receiving substrate that is placed in proximity to the target substrate. Laser induced forward transfer is typically used to transfer opaque thin films, typically metals, from a pre-coated laser transparent support, typically glass, SiO₂, Al₂O₃, SrTiO₃, etc., to the receiving substrate. Various methods of laser-induced forward transfer are described in, for example, the following U.S. patents and publications incorporated herein by reference: U.S. Patent No. 4,752,455 to Mayer, U.S. Patent No. 4,895,735 to Cook, U.S. Patent No. 5,725,706 to Thoma et al, U.S. Patent No. 5,292,559 to Joyce, Jr. et al, U.S. Patent No. 5,492,861 to Opower, U.S. Patent No. 5,725,914 to Opower, U.S. Patent No. 5,736,464 to Opower, U.S. Patent No. 4,970,196 to Kim et al, U.S. Patent No. 5,173,441 to Yu et al, and Bohandy et al, "Metal Deposition from a Supported Metal Film Using an Excimer Laser, J. Appl. Phys. 60 (4) 15 August 1986, pp 1538 - 1539. Because the film material is vaporized by the action of the laser, laser induced forward transfer is inherently a homogeneous, pyrolytic technique and typically cannot be used to deposit complex crystalline, multi-component materials or materials that have a crystallization temperature well above room temperature because the resulting deposited material will be a weakly adherent amorphous coating. Moreover, because the material to be transferred is vaporized, it becomes more reactive and can more easily become degraded, oxidized or contaminated. The method is not well suited for the transfer of organic materials, since many organic materials are fragile and thermally labile and can be irreversibly damaged during deposition. Moreover, functional groups on an organic polymer can

be irreversibly damaged by direct exposure to laser energy. Other disadvantages of the laser induced forward transfer technique include poor uniformity, morphology, adhesion, and resolution. Further, because of the high temperatures involved in the process, there is a danger of ablation or sputtering of the support, which can cause the incorporation of impurities in the material that is deposited on the receiving substrate. Another disadvantage of laser induced forward transfer is that it typically requires that the coating of the material to be transferred be a thin coating, generally less that 1 μ m thick. Because of this requirement, it is very time-consuming to transfer more than very small amounts of material.

In a simple variation of the laser induced forward deposition technique, the target substrate is coated with several layers of materials. The outermost layer, that is, the layer closest to the receiving substrate, consists of the material to be deposited and the innermost layer consists of a material that absorbs laser energy and becomes vaporized, causing the outermost layer to be propelled against the receiving substrate. Variations of this technique are described in, for example, the following U.S. patents and publications incorporated herein by reference: U.S. Patent No. 5,171,650 to Ellis et al, U.S. Patent No. 5,256,506 to Ellis et al, U.S. Patent No. 4,987,006 to Williams et al, U.S. Patent No. 5,156,938 to Foley et al and Tolbert et al, "Laser Ablation Transfer Imaging Using Picosecond Optical pulses: Ultra-High Speed, Lower Threshold and High Resolution" Journal of Imaging Science and Technology, Vol. 37, No. 5, Sept./Oct. 1993pp.485-489. A disadvantage of this method is that, because of the multiple layers, it is difficult or impossible to achieve the high degree of homogeneity of deposited material on the receiving substrate required.

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for example, for the construction of electronic devices, sensing devices or passivation coatings.

Therefore, there is a strong need for devices and methods for transferring materials for uses such as in electronic devices, sensing devices or passivation coatings with in such a way that desired properties of the materials are preserved or enhanced. For example, there is a need for a method to transfer powders or particulate materials so that they retain their bulk properties. With respect to novel materials such as organic polymers that are incorporated into electronic devices, there is a need for a method to transfer these materials in such a way that their structural and chemical integrity is retained.

Summary of the Invention

It is an object of the present invention to provide devices, materials and methods for depositing a material on a substrate wherein a pattern can be created directly on the substrate without the use of a mask.

It is an object of the present invention to provide a device and method that is useful for depositing a wide range of materials such as complex polymeric materials or complex electronic materials, with no damage to the starting material.

It is a further object of the present invention to provide a device and method for depositing a material on a substrate wherein the deposition can be carried out in ambient conditions, that is, at atmospheric pressure and at room temperature.

It is a further object of the present invention to provide a device ad method for depositing a

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material on a substrate by laser induced deposition wherein the spatial resolution of the deposited material can be as small as 1 μ m.

It is an object of the present invention to provide equipment and a method for creating an electronic device, sensor, or passivation coating by depositing a materials on a substrate in a controlled manner wherein the process can be computer-controlled.

It is an object of the present invention to provide equipment and a method for creating an electronic device, sensor or passivation coating by depositing a materials on a substrate in a controlled manner wherein it is possible to switch rapidly between different materials to be deposited on the substrate.

These and other objects are achieved by a device and method for depositing a material onto a receiving substrate, the device comprising a source of pulsed laser energy, a receiving substrate, and a target substrate. The target substrate comprises a laser transparent support having a back surface and a front surface. The front surface has a coating that comprises a mixture of the transfer material to be deposited and a matrix material. The matrix material has the property that, when it is exposed to pulsed laser energy, it is more volatile than the transfer material. The source of pulsed laser energy can be positioned in relation to the target substrate so that pulsed laser energy can be directed through the back surface of the target substrate and through the laser-transparent support to strike the coating at a defined location with sufficient energy to volatilize the matrix material at the location, causing the coating to desorb from the location and be lifted from the surface of the support. The receiving substrate can be positioned in a spaced relation to the target substrate so that

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the transfer material in the desorbed coating can be deposited at a defined location on the receiving substrate and so that the matrix material, or decomposition products thereof, in the desorbed coating can migrate from the space between the receiving substrate and the target substrate.

The source of pulsed laser energy and the target substrate can be moved with respect to each other so that after the coating desorbs at one location on the target substrate, the pulsed laser energy can be directed to another location on the target substrate where the coating has not yet desorbed. The source of pulsed laser energy and the receiving substrate can be moved with respect to each other so that the transfer material can be deposited in a pattern. The source of pulsed laser energy can also be directed through a transparent region of the target substrate, or the target substrate can be moved completely out of the way so that the pulsed laser energy strikes the receiving substrate directly and interacts with the receiving substrate or with material already deposited on the receiving substrate. This can be done, for example, to roughen the surface of the receiving substrate or to modify the composition and properties of material that has been deposited.

Brief Description of the Drawings

A more complete appreciation of the invention will be readily obtained by reference to the following Description of the preferred Embodiments and the accompanying drawings.

Figure 1 is a schematic representation of the apparatus of the present invention.

Figures 2a and 2b are schematic representations of the laser transparent substrate, the coating and the receiving substrate before (2a) and after (2b) the depositing of the transfer material on the

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receiving substrate.

Detailed Description of the Preferred Embodiments

As schematically illustrated in Figure 1, the apparatus of the present invention includes a pulsed laser 12 that emits pulsed laser energy as depicted by arrow 14. The pulsed laser is positioned so that laser pulses travel through the back surface of the target substrate and through the laser transparent support 15 to strike the coating 16, which comprises a mixture of a transfer material and a matrix material. The receiving substrate 18 is positioned so that when the coating desorbs from the target substrate, the transfer material is deposited on the receiving substrate. The laser, the target substrate and the receiving substrate are connected to laser positioning means 20, target substrate positioning means 22 and receiving substrate positioning means 24, respectively. Figures 2a and 2b schematically illustrate the effects of exposing the coating 16 to the pulsed laser energy 14, whereby the coating 16 desorbs from the surface of the target substrate so that the transfer material 26 is deposited onto the receiving substrate 18.

The receiving substrate can be any material, planar or non-planar onto which one may wish to deposit a transfer material. The receiving substrate may be any solid material including, but not limited to, silicon, glass, plastics, metals, and ceramics. The present invention is particularly useful in creating electronic devices such as passive and active components of printed circuit boards (PCBs) or in creating chemoselective coatings for chemical sensors such as surface acoustic wave (SAW) resonators.

The transfer material can be any material that one may wish to deposit on a substrate in a

	Docket No.: N.C. 79,702 PATENT APPLICATION Inventor's Name: Douglas B. Chrisey, R. Andrew McGill and Alberto Pique
1	defined pattern, including, but not limited to the following:
2	Metals, including, but not limited to silver, nickel, gold, copper, chromium, titanium,
3	aluminum, platinum, palladium, etc., and alloys thereof;
4	Ceramics, including, but not limited to alumina (Al ₂ O ₃), silica and other glasses, and
5	dielectrics (see below);
6	Dielectrics, including, but not limited to alumina, magnesium oxide (MgO), yttrium
7	oxide(Y ₂ O ₃), zirconium oxide (ZrO ₂), cerium oxide (CeO ₂), etc.;
8	Ferroelectrics, including, but not limited to barium titanate (BaTiO ₃), strontium titanate
9	(SrTiO ₃), lead titanate (PbTiO ₃), lead zirconate (PbZrO ₃), potassium niobate (KNbO ₃), strontium
10	bismuth tantalate (SrBi ₂ Ta ₂ O ₉), (Ba,Sr)TiO3, and solid solution stoichiometric variations thereof,
11	etc.;
12	Piezoelectrics, including, but not limited to the above mentioned ferroelectrics, quartz, AlN,
13	etc.;
14	Ferrites, including but not limited to yttrium iron garnet (Y ₃ Fe ₅ O ₁₂), barium zinc ferrite
15	$(Ba_2Zn_2Fe_{12}O_{19})$, hexagonal ferrites such as barium ferrite, spinel ferrites such as nickel zinc ferrites,
16	manganese zinc ferrite, magnetite (Fe ₃ O ₄), etc.;
17	Electro-optical ceramics, including, but not limited to lithium niobate (LiNbO ₃), lithium
18	tantalate (LiTaO ₃), cadmiun telluride (CdTe), zinc sulfide (ZnS), etc.;
19	Ceramic superconductors, including, but not limited to YBa ₂ Cu ₃ O _{7-x} (YBCO),
20	Tl ₂ CaBa ₂ Cu ₃ O ₁₂ , La _{1.4} Sr _{0.6} CuO _{3.1} , BiSrCACuO, BaKBiO, halide doped fullerines,etc.;

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- Chalcogenides, including, but not limited to SrS, ZnS, CaS, PbS, etc.;
- Chemoselective materials (see below); 2
- Bioselective materials (see below): 3
- Semiconductors, including, but not limited to Si, Ge, GaAs, CdTe, etc.; 4
- 5 Phosphors, including, but not limited to SrS:Eu, SrS:Ce, ZnS:Ag, Y₂O₂:Eu, Zn₂SiO₄:Mn, 6 etc.and

Transparent conductive oxides, including, but not limited to indium tin oxide, zinc oxide, etc.

For example, if the receiving substrate is a component of an electronic device, the transfer material can be a material having particular desired electronic properties. Examples of electronic materials include metals, dielectrics, ferroelectrics, ferrites, ferrimagnets, ferromagnets, semiconductors, phosphors and electrically conducting organic polymers.

If the receiving substrate is a component of a chemical or biological sensor, the transfer material can be a material that interacts selectively with a particular chemical or biological analyte. Criteria for selecting chemically selective materials for chemical sensing devices are described in detail in McGill et al, "Choosing Polymer Coatings for Chemical Sensors", CHEMTECH, Vol 24, No. 9, pp 27-37 (1994), the disclosure of which is incorporated herein by reference. Examples of chemoselective materials include SXFA (poly(oxy{methyl]4-hydroxy-4.4,bis(trifluoromethyl)but-1en-1-yl] silylene})), P4V (poly(4-vinylhexafluorocumyl alcohol). Other examples of chemoselective materials include perfluoro-polyethers terminated with a variety of functional groups such as CF₃CH₂OH, polyethylene imines, polysiloxanes, alkylamino pyridyl substituted polysiloxanes,

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polytetrafluoroethylene, polysilanes, polyesters, polyvinylaldehydes, polyisobutylene, polyvinylesters, polyalkenes, zeolites, aerogels, porous carbon, metals, silicalites, clay materials, cellulose materials, polyanilines, polythiophenes, polypyrroles, fullerenes, cyclodextrins, cyclophanes, calixeranes, crown ethers, and organic dyes.

Examples of biochemical materials that can be deposited with the present invention include proteins, oligopeptides, polypeptides, whole cells, biological tissue, enzymes, cofactors, nucleic acids, DNA, RNA, antibodies (intact primary, polyclonal, and monoclonal), antigens, oligosaccharides, polysaccharides, oligonucleotides, lectins, biotin, streptavidin, and lipids.

The receiving substrate may be a component of a physical sensing device, such as, for example, a magnetic sensor, optical sensor, temperature sensor, pressure sensor or gas flow sensor. The transfer material may then be an appropriate sensing material, such as a magnetic sensing material, optical sensing material, temperature sensing material, pressure sensing material or gas flow sensing material. Examples of physical sensing transfer materials include magnetic-nonmagnetic multilayers or resonant magnetic oscillators for magnetic sensing, thin film thermocouples for temperature sensing, piezoelectic films or resonators for pressure sensing and simple resistive heater-thermocouple combinations for gas flow sensing.

In many instances, the desired properties of a material are due to the presence of functional groups in the material. For example chemoselective polymers such as SXFA and P4V derive their chemoselectivity from functional groups that extend outward from the polymer backbone. A purpose of the present invention is to provide a way to deposit these polymers onto a substrate without

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damaging or disrupting the functional groups. As another example, some materials have different electronic, mechanical and thermal properties depending on whether they are in bulk form or in the form of single crystals. For instance, a large grain size is desirable for ferroelectrics to achieve a near bulk dielectric constant and large crystalline platelets are desirable for ferrites to minimize demagnetizing forces. The transfer material in the present invention can be in any form ranging from single crystallites to nanophase powders to micron size particulates, depending on the particular intended use for the transferred material and whether bulk-like properties are desired. A purpose of the present invention is to provide a way to deposit such materials so that the desired form of the material is preserved or even improved (such as in depositing material in such a way that it is better connected or bonded than the original material). Typical particle sizes for the transfer material may range from about 10 nm to about 20 μ m. For close packing of the transfer material, the transfer material can comprise particles of different size classes, so that smaller particles can fit into interstices between larger particles. For example, for face centered cubic packing of particles, the highest packing density can be achieved by providing particles of three different sizes wherein the ratio of particle sizes is 1: less than .414: less than .225.

The transfer material may also be coated particles, such as metal or ceramic particles coated with organic materials such as organic precursors.

It is the presence of the matrix material that provides the advantages that the present invention has over methods such as laser induced forward transfer (LIFT). The matrix material is selected primarily according to two criteria: the matrix material must be compatible with the transfer

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material so that the matrix material and the transfer material can be combined into a mixture to form the coating on the front surface of the laser transparent support, and the matrix material must have the property of being more volatile than the transfer material when the coating is exposed to pulsed laser energy so that when the coating is exposed to pulsed laser energy, the matrix material volatilizes or vaporizes, thereby causing the coating to desorb from the surface of the laser transparent support. The amount of matrix material that is used in the coating relative to the amount of the transfer material can be any amount sufficient to accomplish the purposes described above. Typically, the amount will vary according to the particular matrix material and transfer material.

Other factors that can be taken into account in selecting the optimum matrix material to go with a particular transfer material include the ability of the matrix material to dissolve or form a colloidal or particulate suspension with the particular transfer material, the melting point, heat capacity, molecular size, chemical composition, spectral absorption characteristics and heat of vaporization of the matrix material (factors that affect the ability of the matrix material to desorb and lift the transfer material from the target substrate) and the reactivity or nonreactivity of the matrix material towards the transfer material.

The matrix material may also serve other functions. For example, the presence of the matrix material may aid in the construction of the coating on the target substrate by helping to hold the transfer material in place on the target substrate, especially if the transfer material is a powder. At the same time, the matrix material may help prevent the transfer material from binding too tightly to the surface of the target substrate. The matrix material may also provide a source of particle

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coating for transfer material that is in the form of a powder and provide a source of additives, binders and dispersants for the transfer material.

Another consideration is any special ability a particular matrix material may have to impart protection to a particular transfer material from damage during the lasing, desorption and transfer to the receiving substrate. For example, a matrix material that absorbs laser energy at the same wavelength as an important functional group on the transfer material may serve to protect the transfer material from damage from exposure to the laser energy. Alternatively, a matrix material may be used that absorbs at a wavelength in a spectral region substantially outside that of the transfer material. In this instance, the matrix material transforms pulsed laser energy into kinetic energy, and the kinetic energy is imparted to the transfer material. Examples of matrix materials include but are not limited to addition polymers (see below), condensation polymers (see below), photoresist polymers (see below), water, aryl solvents, especially toluene, acetophenone and nicotinic acid, arene compounds (e.g. naphthalene, anthracene, phenanthrene), t-butylalcohol, halogenated organic solvent, hydrocarbons, ketones, alcohols, ethers, esters, carboxylic acids, phenols and phosphoric acid.

The matrix material may also be a polymer that decomposes or "unzips" into volatile components when exposed to laser energy. The volatile decomposition products then act to propel or lift the transfer material into the gas phase. The polymeric matrix material acts as a propellant and at room temperature the propellant products are volatilized away while the transfer material is deposited as a thin film on the receiving substrate.

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Unzipping mechanisms are typically catalyzed by a photon that is absorbed by the polymer and leads to chain cleavage, formation of a free radical (The free radical can be formed either by a thermally driven process or by a photochemical process) in the chain which then travels down the polymer chain leading to a chain unzipping that can produce the monomer species. The monomer, ejected at high kinetic energies, imparts some of this energy to the transfer material mixed with the polymer. One general controlling factor for depolymerization or unzipping of addition polymers is the ceiling temperature of the polymer. At the ceiling temperature, the rates of polymerization and depolymerization are equal. At temperatures above the ceiling temperature, depolymerization dominates polymerization. Laser radiation allows the high ceiling temperatures required for depolymerization to be reached between radiation pulses.

In general, polymeric propellants that are suitable candidates for consideration as matrix materials are taken from the class of polymers called addition polymers. As a subclass of addition polymers, the suitable candidate materials are typically sterically crowded and are generally thermally unstable. The general polymer classes that are of interest with known properties include poly(alkenes), poly(acrylics), poly(methacrylics), poly(vinyls), poly(vinylketones), poly(styrenes), poly(oxides) or polyethers. In general, addition polymers with alpha substituted structures consistently exhibit lower ceiling temperatures than their unsubstituted parent species and are strong candidate materials. Polymers from the class of materials called condensation polymers, as well as the class of materials called photoresist polymers, may also have some utility, especially if they decompose to volatile materials. The spectrum of candidate materials is wide and many polymers

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propellants can be used as the matrix material. Not all will be ideal in all characteristics. For example, repolymerization of a polymeric matrix material on the receiving substrate may be a problem with some materials. Other factors to be considered in the selection of the matrix material include the absorption of UV laser radiation, volatility of native propellant material, efficiency of the unzipping process, products of unzipping or decomposition and their volatilty/toxicity, kinetic energy imparted by the propellant, degree of repolymerization, inertness of binder material, inertness of unzipped or decomposed propellant, cost, availability, purity, and processability with the material of interest to be deposited.

Specific polymeric matrix materials include, but are not limited to, the following: polyacrylic acid -butyl ester, nitrocellulose, poly(methacrylic acid)-methyl ester (PMMA), poly(methacrylic acid)-n butyl ester (PBMA), poly(methacrylic acid)-t butyl ester (PtBMA), polytetrafluoroethylene (PTFE), polyperfluoropropylene, poly N-vinyl carbazole, poly(methyl isopropenyl ketone), poly alphamethyl styrene, polyacrylic acid, alpha phenyl-, methyl ester, polyvinylacetate, polyvinylacetate with zincbromide present, poly(oxymethylene), phenol-formaldehyde positive photoresist resins and photobleachable aromatic dyes.

The matrix material may also contain components that assist in the bonding of the transfer material to the receiving substrate or that assist in the bonding of particles of the transfer material to each other after they are deposited on the receiving substrate.

Examples of possible transfer material - matrix material combinations for the transfer of electronic materials include alumina (transfer material) with phosphoric acid (matrix material),

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barium titanate (transfer material) with poly(methacrylic acid), n-butyl ester (PBMA) (matrix material), yttrium iron garnet (transfer material) with poly(methacrylic acid), n-butyl ester (PBMA) (matrix material), and nickel (transfer material) with KPR, (a phenol-formaldehyde positive photoresist polymer) (matrix material).

Examples of possible transfer material - matrix material combinations for the transfer of chemoselective polymers are SXFA (poly(oxy{methyl[4-hydroxy-4,4,bis(trifluoromethyl)but-1-en-1-yl] silylene})) (transfer material) with *t*-butanol (matrix material) and P4V (poly(4-vinylhexafluorocumyl alcohol)) (transfer material) with acetophenone (matrix material).

The transfer material and the matrix material may be combined to form the coating on the front surface of the laser transparent support in any manner that is sufficient to carry out the purpose of the invention. If the transfer material is soluble to some extent in the matrix material, the transfer material may be dissolved in the matrix material. Alternatively, if the transfer material is not soluble in a suitable solvent, the transfer material may be mixed with a matrix material to form a colloidal or particulate suspension or condensed phase. Still another alternative is to combine the matrix material and the transfer material with a solvent that volatilizes after the mixture is applied to the laser transparent support. The matrix material can also include soluble or insoluble dopants, that is, additional compounds or materials that one may wish to deposit onto the film.

The mixture of the transfer material and the matrix material may be applied to the front surface of the laser transparent support by any method known in the art for creating uniform coatings on a surface, including, for example, by spin coating, ink jet deposition, jet vapor deposition, spin

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spray coating, aerosol spray deposition, electrophoretic deposition, pulsed laser deposition, matrix assisted pulsed laser evaporation, thermal evaporation, sol gel deposition, chemical vapor deposition. sedimentation and print screening. Typically, the mixture of the transfer material and the matrix material will be applied to the front surface of the laser transparent substrate to form a coating that is between about .1 μ m and about 100 μ m in thickness. Preferably, the coating is greater than about 1 μ m in thickness, and, most preferably, is between about 1 μ m and about 20 μ m in thickness. The thicker the coating, the more of the transfer material can be transferred at one time, which is an advantage of the present invention over laser transfer methods that use thin films. On the other hand. a coating that is too thick will not desorb when exposed to the pulsed laser.

If the mixture of the transfer material and the matrix material is a liquid at room temperature. the mixture may be coated onto the front surface of the laser transparent support and then the mixture may be frozen to form a solid coating. The target substrate may be kept frozen while the coating is being exposed to a source of laser energy during the deposition process.

The laser transparent support is typically planar, having a front surface that is coated with the mixture of the transfer material and the matrix material and a back surface that can be positioned so that laser energy can be directed through the support. The composition of the laser transparent support is selected in accordance with the particular type of pulsed laser that is used. For example, if the laser is a UV laser, the laser transparent support may be a UV-transparent material including, but not limited to fused silica or sapphire. If the laser is an IR laser, the laser transparent support may be an IR-transparent material including, but not limited to plastic, silicon, fused silica, or sapphire.

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Similarly, if the laser is a visible laser, the laser transparent support may be a material that is transparent in the visible range, including, but not limited to soda-lime and borosilicate glasses.

Any suitable source of laser energy may be used in the present invention. In general, a pulsed laser is preferred. (As used herein, the terms "pulsed laser" and "source of pulsed laser energy" are used interchangeably to refer to any device that creates a pulsed laser beam.) Lasers for use in accordance with the present invention can be any type such as are generally used with other types of laser deposition. Pulsed lasers are commercially available within the full spectral range from UV to IR. Typically, such lasers emit light having a wavelength in the range of about 157 nm - 1100 nm, an energy density of about 0.05 - 10 J/cm² (typically about 0.1 - 2.0 J/cm²), a pulsewidth of about 10^{-12} - 10^{-6} second and a pulse repetition frequency of about 0 to greater than 20,000 Hz. In general, energy density (fluence) affects morphology; higher energies tend to produce deposited films that have larger particles. Examples of suitable lasers include, but are not limited to, pulsed gas lasers such as excimer lasers, i.e. F_2 (157 nm), ArF (193 nm), KrF (248 nm). XeCl (308 nm), XeF (351 nm), CO₂, nitrogen, metal vapor, etc., pulsed solid state lasers such as Nd:YAG, Ti:Sapphire, Ruby, diode pumped, semiconductor, etc., and pulsed dye laser systems. Typically, the particular laser is selected with regard to the absorption wavelengths of the matrix material.

The source of pulsed laser energy, the target substrate and the receiving substrate can be positioned with respect to each other and moved with respect to each other by any means known in the art for supporting a laser, target substrate and receiving substrate and moving them in a controlled and defined manner. For example, similar positioning means and moving means for a

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laser, target and receiving substrate are known in the fields of laser transfer deposition and laser induced forward transfer. The laser may be positioned in any location that provides an optical path between itself and the target substrate so that sufficient laser energy can be directed to defined positions on the target substrate. The dimensions of the pulsed laser beam can be controlled by any means known in the art so that only a precisely defined area of the target substrate is exposed to the pulsed laser energy and so that only a precisely defined portion of the coating desorbs. The receiving substrate should be positioned so that when the coating on the target substrate is desorbed, the transfer material can be deposited at a defined location on the receiving substrate. Also, there should be enough space between the target substrate and the receiving substrate so that volatilized matrix material, or byproducts from laser-induced decomposition of the matrix material, can escape from the space between the target substrate and the receiving substrate. Preferably, the receiving substrate is positioned about 10 to about 100 μm from the coating on the front surface of the target substrate. The laser, target substrate, and the receiving substrate should be moveable with respect to each other so that the transfer material can be deposited in a pattern and so that after the coating desorbs at one location on the target substrate, the pulsed laser energy can be directed to another location on the target substrate where the coating has not yet desorbed. For example, to deposit a line of material on the receiving substrate, the laser is moved with respect to the target substrate and the receiving substrate, which may be held stationary with respect to each other. As the laser moves with respect to the substrate, it directs laser energy to a new location on the target substrate where the coating has not yet desorbed, and causes the transfer material to be deposited onto a new location on the

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receiving substrate. The successive locations may overlap to the extent necessary to create a continuous line of material on the receiving substrate. To increase the thickness of a deposit at a particular location, the laser and the receiving substrate are held stationary with respect to each other and the target substrate is moved with respect to the laser and the receiving substrate so that as the target substrate moves with respect to the laser, laser energy is directed to a new location on the target substrate where the coating has not yet desorbed and since the laser and the receiving substrate are not moved with respect to each other, the transfer material is deposited onto the same location on the receiving substrate in an increasingly thickened deposit. (As used herein, the terms "moving [a] with respect to [b]" or "moving [a] and [b] with respect to each other" mean that either [a] or [b] can be moved to effect a change in their relative position.)

The apparatus of the present invention can be adapted so that a plurality of different transfer materials can be deposited consecutively onto a receiving substrate. This may be done by providing a plurality of target substrates each having a different coating with a different transfer material and providing a way to consecutively move each target substrate into a position for depositing material from that target substrate onto the receiving substrate. Consecutive deposition of different transfer materials can also be accomplished by providing a target substrate that is subdivided into a plurality of different subregions that each have a different coating with a different transfer material and providing a way to select a particular subregion and deposit the transfer material from that subregion onto the receiving substrate.

The apparatus of the present invention can also be adapted so that an entire pattern of transfer

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material is deposited simultaneously on a patterned substrate

Having described the invention, the following examples are given to illustrate specific applications of the invention, including the best mode now known to perform the invention. These specific examples are not intended to limit the scope of the invention described in this application.

EXAMPLES

Example 1: Deposition of Alumina (Al₂O₃)

The coating for the target substrate for the deposition of alumina was prepared by mixing 2 grams of alumina, in the form of random-shaped powders having an average particle size of $0.3~\mu m$, with 1 ml of a matrix material, phosphoric acid, in 9 ml of methanol and then applying the solution to one side of a 5 cm diameter fused silica disc by spin coating to form an Al3O3/H3PO4 coating about 1 to 2 μm thick. Using an excimer pulsed laser operating at 248 nm and at a fluence of 300 mJ/cm², focused through the fused silica disk to strike the coating in a 25 μm laser spot, it was possible to transfer the alumina powders from the silica disc to a receiving substrate surface located 25 μm away. Each laser shot produced a 25 μm disc-shaped deposit about 1 μm thick. To create a line of deposited BTO on the substrate, the laser was moved in a line relative to the substrate and the receiving substrate. To increase the thickness of the deposit at a particular location, the laser and the receiving substrate were held stationary to each other for several shots while the target substrate was moved. With this technique, a dielectric layer for a capacitor was formed.

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Example 2: Deposition of Barium Titanate (BaTiO₃, also referred to as "BTO")

The coating for the target substrate for the deposition of barium titanate was prepared by mixing 1 gram of BTO, in the form of random-shaped powders having an average particle size of 1 μ m, with 0.05 grams of a matrix material, poly(methacrylic acid), n-butyl ester (PBMA) in 10 ml of chloroform and then applying the solution to one side of a 5 cm diameter fused silica disc by spin coating to form a BTO/PBMA coating about 1 to 2 μ m thick. Using an excimer pulsed laser operating at 248 nm and at a fluence of 400 mJ/cm², focused through the fused silica disk to strike the coating in a 25 μ m laser spot, it was possible to transfer the BTO powders from the silica disc to a receiving substrate surface located 25 μ m away. Each laser shot produced a 25 μ m disc-shaped deposit about 1 μ m thick. To create a line of deposited BTO on the substrate, the laser was moved in a line relative to the substrate and the receiving substrate. To increase the thickness of the deposit at a particular location, the laser and the receiving substrate were held stationary to each other for several shots while the target substrate was moved. With this technique, a dielectric layer for a capacitor was formed.

Example 3: Deposition of Yttrium Iron Garnet (Y₃Fe₅O₁₂, also referred to as "YIG")

The coating for the target substrate for the deposition of yttrium iron garnet was prepared by mixing 1 gram of YIG, in the form of spherical powders having an average particle size of 1 μ m, with 0.05 grams of a matrix material, poly(methacrylic acid), n-butyl ester (PBMA) in 10 ml of chloroform and then applying the solution to one side of a 5 cm diameter fused silica disc by spin coating to form a YIG/PBMA coating about 1 to 2 μ m thick. Using an excimer pulsed laser

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operating at 248 nm and at a fluence of 400 mJ/cm², focused through the fused silica disk to strike the coating in a 25 μ m laser spot, it was possible to transfer the YIG powders from the silica disc to a receiving substrate surface located 25 μ m away. Each laser shot produced a 25 μ m disc-shaped deposit about 1 μ m thick. To create a line of deposited BTO on the substrate, the laser was moved in a line relative to the substrate and the receiving substrate. To increase the thickness of the deposit at a particular location, the laser and the receiving substrate were held stationary to each other for several shots while the target substrate was moved. With this technique, a ferrite core for an inductor was formed.

Example 4: Deposition of Nickel

The coating for the target substrate for the deposition of nickel was prepared by mixing 2 grams of nickel, in the form of spherical powders having an average particle size of 1 μ m, with 10 ml of a matrix material, diazonaphthoquinone-novolac (a phenol-formaldehyde positive photoresist polymer sold by Kodak under the tradename "KPR") and then applying the solution to one side of a 5 cm diameter fused silica disc by spin coating to form a nickel/KPR coating about 1 to 2 μ m thick. Using an excimer pulsed laser operating at 248 nm and at a fluence of 450 mJ/cm², focused through the fused silica disk to strike the coating in a 40 μ m laser spot, it was possible to transfer the YIG powders from the silica disc to a receiving substrate surface located 25 μ m away. Each laser shot produced a 40 μ m disc-shaped deposit about 0.3 μ m thick. To create a line of deposited nickel on the substrate, the laser was moved in a line relative to the substrate and the receiving substrate. To increase the thickness of the deposit at a particular location, the laser and the receiving substrate

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- were held stationary to each other for several shots while the target substrate was moved. With this technique, various lines of deposited nickel were formed.
- Obviously, many modifications and variations of the present invention are possible in light

 of the above teachings. It is therefore to be understood that, within the scope of the appended claims,

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Claims

What is claimed is:

1. An apparatus for depositing a transfer material onto a receiving substrate, the apparatus

comprising

a source of pulsed laser energy,

a receiving substrate, and

a target substrate comprising a laser-transparent support having a back surface and a front

surface, wherein the front surface has a coating that comprises a mixture of the transfer material

to be deposited and a matrix material, wherein the matrix material has the property of being or

becoming more volatile than the transfer material when exposed to pulsed laser energy,

means for positioning the source of pulsed laser energy in relation to the target substrate

so that pulsed laser energy can be directed through the back surface of the target substrate and

through the laser-transparent support to strike the coating at a defined location with sufficient

energy to cause the coating to desorb from the location and be lifted from the surface of the

support,

means for positioning the receiving substrate in a spaced relation to the target substrate so

that the matrix material, or decomposition products thereof, in the desorbed coating can migrate

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from the space between the receiving substrate and the target substrate, and so that the transfer material in the desorbed coating can be deposited at a defined location on the receiving substrate.

2. The apparatus of claim 1 wherein the transfer material is in the form of particles and wherein the coating is a colloidal or particulate suspension of the transfer material in the matrix material.

3. The apparatus of Claim 1 wherein the transfer material is in the form of particles having a grain size of between about 10 nm and about 20 μ m.

4. The apparatus of Claim 1 wherein the transfer material is a mixture of particles having different grain sizes.

5. The apparatus of Claim 1 wherein the transfer material is an electronic material selected from the group consisting of metals, dielectrics, ferroelectrics, ferrites, ferrimagnets, ferromagnets, phosphors, and semiconductors.

6. The apparatus of Claim 1 wherein the transfer material is a polymer.

7. The apparatus of Claim 1 wherein the transfer material comprises metal or ceramic particles coated with organic precursors.

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8. The apparatus of Claim 1 wherein the receiving substrate is a component of a sensing device and the transfer material is a sensing material selected from the group consisting of chemically selective material, biologically selective material, magnetic sensing material, optical sensing material, pressure sensing material, temperature sensing material, porosity selective material and gas flow sensing material.

- 9. The apparatus of Claim 1 wherein the matrix material is a material that decomposes into volatile components when exposed to pulsed laser energy.
- 10. The apparatus of Claim 9 wherein the matrix material is an addition polymer.
- 11. The apparatus of Claim 9 wherein the matrix material is selected from the group consisting of poly(alkenes), poly(acrylics), poly(methacrylics), poly(vinyls), poly(vinylketones), poly(styrenes), poly(oxides) and polyethers.
- 12. The apparatus of Claim 9 wherein the matrix material is selected from the group consisting of polyacrylic acid –butyl ester, nitrocellulose, poly(methacrylic acid)-methyl ester (PMMA), poly(methacrylic acid)-n butyl ester (PBMA), poly(methacrylic acid)-t butyl ester (PtBMA), polytetrafluoroethylene (PTFE), polyperfluoropropylene, poly N-vinyl carbazole, poly(methyl

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isopropenyl ketone), poly alphamethyl styrene, polyacrylic acid, alpha phenyl-, methyl ester, polyvinylacetate, polyvinylacetate/zincbromide, poly(oxymethylene), phenol-formaldehyde positive photoresist resins and photobleachable aromatic dyes.

13. The apparatus of Claim 1 wherein the matrix material is selected from the group consisting of water, aryl solvents, arene solvents, halogenated organic solvents, hydrocarbons, ketones, esters, ethers, carboxylic acids, phenols and phosphoric acid.

14. The apparatus of Claim 1 further including means for moving the source of pulsed laser energy and the target substrate with respect to each other so that after the coating desorbs at one location on the target substrate, the pulsed laser energy can be directed to another location on the target substrate where the coating has not yet desorbed, and

means for moving the source of pulsed laser energy and the receiving substrate with respect to each other so that the transfer material can be deposited in a pattern.

15. The apparatus of Claim 1 wherein the apparatus further includes a mask interposed between the source of laser energy and the target substrate.

16. The apparatus of Claim 1 wherein the coating on the front surface of the target substrate has been formed by a process of combining the transfer material and the matrix material to form a

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mixture and applying the mixture to the front surface of the target substrate by a coating method selected from the group consisting of spin coating, ink jet deposition, jet vapor deposition, spin spray coating, aerosol spray deposition, electrophoretic deposition, pulsed laser deposition, matrix assisted pulsed laser evaporation, thermal evaporation, sol gel deposition, chemical vapor deposition, sedimentation and screen printing.

- 17. The apparatus of Claim 1 wherein the coating on the front surface of the target substrate has a thickness of between about .1 μ m and about 100 μ m.
- 18. The apparatus of Claim 1 wherein the coating on the front surface of the target substrate has a thickness of between about 1 μ m and about 20 μ m.
- 19. The apparatus of Claim 1, further including means to position the source of pulsed laser energy with respect to the receiving substrate so that the pulsed laser energy can be directed to strike the receiving substrate whereby the receiving substrate can be pretreated or whereby a transfer material deposited on the substrate can be annealed or etched.
- 20. A method for depositing a transfer material onto a receiving substrate, the method comprising the steps of

providing a source of pulsed laser energy,

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providing a receiving substrate

providing a target substrate comprising a laser-transparent support having a back surface and a front surface, wherein the front surface has a coating that comprises a mixture of the transfer material and a matrix material, wherein the matrix material has the property of being or becoming more volatile than the transfer material when exposed to pulsed laser energy,

positioning the source of pulsed laser energy in relation to the target substrate and exposing the target substrate to pulsed laser energy so that the pulsed laser energy is directed through the back surface of the target substrate and through the laser-transparent support to strike the coating at a defined location with sufficient energy to volatilize the matrix material at the location, causing the coating to desorb from the location and be lifted from the surface of the support,

positioning the receiving substrate in a spaced relation to the target substrate so that the transfer material in the desorbed coating is deposited at defined location on the receiving substrate and so that the matrix material, or decomposition products thereof, in the desorbed coating can migrate from the space between the receiving substrate and the target substrate.

- 21. The method of Claim 20 wherein the transfer material is in the form of particles and wherein the coating is a colloidal or particulate suspension of the transfer material in the matrix material.
- 22. The method of Claim 20 wherein the steps of the method are carried out under ambient

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conditions.

23. The method of Claim 20 wherein the transfer material is in the form of particles having a

grain size of between about 10 nm and about 20 μ m.

24. The method of Claim 20 wherein the transfer material is a mixture of particles having

different grain sizes.

25. The method of Claim 20 wherein the transfer material comprises metal or ceramic particles

coated with organic precursors.

26. The method of Claim 20 wherein the matrix material is a material that decomposes into

volatile components when exposed to pulsed laser energy.

27. The method of Claim 26 wherein the matrix material is an addition polymer.

28. The method of Claim 26 wherein the matrix material is selected from the group consisting of

poly(alkenes), poly(acrylics), poly(methacrylics), poly(vinyls), poly(vinylketones),

poly(styrenes), poly(oxides) and polyethers.

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29. The method of Claim 26 wherein the matrix material is selected from the group consisting of polyacrylic acid –butyl ester, nitrocellulose, poly(methacrylic acid)-methyl ester (PMMA), poly(methacrylic acid)-n butyl ester (PBMA), poly(methacrylic acid)-t butyl ester (PtBMA), polytetrafluoroethylene (PTFE), polyperfluoropropylene, poly N-vinyl carbazole, poly(methyl isopropenyl ketone), poly alphamethyl styrene, polyacrylic acid, alpha phenyl-, methyl ester, polyvinylacetate, polyvinylacetate/zincbromide, poly(oxymethylene), phenol-formaldehyde positive photoresist resins and photobleachable aromatic dves.

- 30. The method of Claim 20 wherein the coating on the front surface of the target substrate has been formed by a process of combining the transfer material and the matrix material to form a mixture and applying the mixture to the front surface of the target substrate by a coating method selected from the group consisting of spin coating, ink jet deposition, jet vapor deposition, spin spray coating, aerosol spray deposition, electrophoretic deposition, pulsed laser deposition, matrix assisted pulsed laser evaporation, thermal evaporation, sol gel deposition, chemical vapor deposition, sedimentation and screen printing.
- 31. The method of Claim 20 wherein the coating on the front surface of the target substrate has a thickness of between about .1 μ m and about 100 μ m.
- 32. The method of Claim 20 wherein the coating on the front surface of the target substrate has a

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thickness of between about 1 μ m and about 20 μ m.

33. The method of Claim 20 wherein the matrix material is selected from the group consisting of

water, aryl solvents, arene solvents, halogenated organic solvents, hydrocarbons, ketones, esters,

ethers, carboxylic acids, phenols and phosphoric acid.

34. The method of Claim 20, further including the steps of moving the source of pulsed laser

energy and the target substrate with respect to each other so that after the coating desorbs at one

location on the target substrate, the source of pulsed laser energy is directed to another location

on the target substrate where the coating has not yet desorbed, and

moving the source of pulsed laser energy and the receiving substrate with respect to each

other so that the transfer material is deposited in a pattern.

35. The method of claim 20 wherein the receiving substrate is a component of an electronic

device and the transfer material is an electronic material selected from the group consisting of

metals, dielectrics, ferroelectrics, ferrites, ferrimagnets, ferromagnets, phosphors and

semiconductors.

36. The method of claim 20 wherein the receiving substrate is a component of a sensing device

and the transfer material is a sensing material selected from the group consisting of chemically

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selective material, biologically selective material, magnetic sensing material, optical sensing material, pressure sensing material, temperature sensing material, and gas flow sensing material.

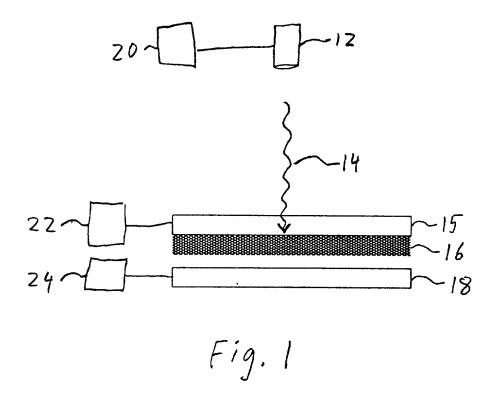
37. The method of claim 20 including the further step of positioning the source of pulsed laser energy with respect to the receiving substrate so that the pulsed laser energy can be directed to strike the receiving substrate whereby the receiving substrate can be pretreated or whereby a transfer material deposited on the substrate can be annealed or etched.

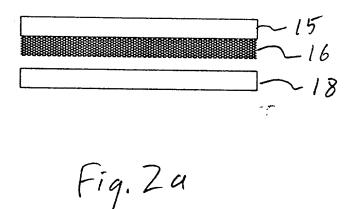
Inventor's Name: Douglas B. Chrisey, R. Andrew McGill and Alberto Pique

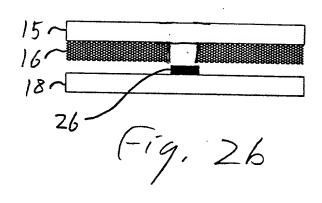
ABSTRACT

An device for depositing a transfer material onto a receiving substrate includes a source of pulsed laser energy, a receiving substrate, and a target substrate. The target substrate comprises a laser transparent support having a back surface and a front surface. The front surface has a coating that comprises a mixture of the transfer material to be deposited and a matrix material. The matrix material is a material that has the property that, when it is exposed to pulsed laser energy, it is more volatile than the transfer material. The source of pulsed laser energy is be positioned in relation to the target substrate so that pulsed laser energy is directed through the back surface of the target substrate and through the laser-transparent support to strike the coating at a defined location with sufficient energy to volatilize the matrix material at the location, causing the coating to desorb from the location and be lifted from the surface of the support. The receiving substrate is positioned in a spaced relation to the target substrate so that the transfer material in the desorbed coating can be deposited at a defined location on the receiving substrate.

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DECLARATION AND POWER OF ATTORNEY

Navy Case No. 79,702 Page 1 of 2

As a below named inventor, I hereby declare that: My residence, post office address and citizenship are as stated below next to my name. I believe I am the original, first, and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: MATRIX-ASSISTED PULSED LASER EVAPORATION DIRECT WRITE. the specification of which is attached hereto.

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign applications for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Number	Country	Filing Date	Priority (Yes/No)	

I hereby claim the benefit under Title 35, United States Code, §120 of any United States applications listed below and. insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of title 35, United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

U.S. Appl. Serial No.	U.S. Filing Date	Status (patented/pending/abandoned)
60/117,468	January 27, 1999	provisional

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorneys/and/or agent/s/ to prosecute this application and transact all business in the Patent and Trademark Office connected therewith, and hereby certify that the Government of the United States has the irrevocable right to prosecute this application:

DIRECT TELEPHONE CALLS TO:

Ralph T. Webb

Thomas E. McDonnell, Reg. No. 26,950 and Ralph T. Webb, Reg. No. 33,047.

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Naval Research Laboratory	Reg. No. 33,047	
Washington, D.C. 20375-5000	(202) 404-1554	:
hereby declare that all statements made herein	of my own knowledge are true and that all statemen	ts made on
nformation and belief are believed to be true; an	nd further that these statements were made with the l	knowledge that
alca statements and the like so made are nunishe	able by fine or imprisonment or both under Costion	1001 aCTH- 1

I ir willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of joint inventor 1: Douglas B. Chrisey DATE: 5/25/99 Inventor's signature: Residence: Bowie, MD, USA Citizenship: US Post Office Address: 12307 Backus Dr., Bowie MD 20720 Full name of joint inventor 2: R. Andrew McGill Inventor's signature: DATE:

Residence: 5821 Hallowing Dr.

SEND CORRESPONDENCE TO:

Associate Counsel (Patents), Code 3008.2

Citizenship: UK

Post Office Address: 5821 Hallowing Dr., Lorton, VA 22079

DECLARATION AND POWER OF ATTORNEY

Navy Case No. 79,702 Page 2 of 2

Full name of joint inventor 3: Alberto Pique

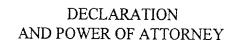
Inventor's signature:

DATE: 5/25/99

Residence: Bowie, MD 20715

Citizenship: US

Post Office Address: 12315 Millstream Drive, Bowie, MD 20715



Navy Case No. 79,702 Page 1 of 2

As a below named inventor, I hereby declare that: My residence, post office address and citizenship are as stated below next to my name. I believe I am the original, first, and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: MATRIX-ASSISTED PULSED LASER EVAPORATION DIRECT WRITE, the specification of which was filed in the U.S. Patent and Trademark Office on May 25, 1999 as U.S. Patent Application No. 09/318,134.

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign applications for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Number	Country	Filing Date	Priority (Yes/No)

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POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorneys/and/or agent/s/ to prosecute this application and transact all business in the Patent and Trademark Office connected therewith, and hereby certify that the Government of the United States has the irrevocable right to prosecute this application:

Thomas E. McDonnell, Reg. No. 26,950 and Ralph T. Webb, Reg. No. 33,047.

SEND CORRESPONDENCE TO:

Associate Counsel (Patents), Code 3008.2

Naval Research Laboratory

Washington, D.C. 20375-5000

DIRECT TELEPHONE CALLS TO:

Ralph T. Webb

Reg. No. 33,047

(202) 404-1554

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full	name	of joint	inventor	1: L	Dougla	is B.	Chrisey
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Inventor's signature:	DATE:
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DECLARATION AND POWER OF ATTORNEY

Navy Case No. 79,702 Page 2 of 2

Full name of joint inventor 2: R. Andrew McGill	
Inventor's signature:	DATE: 7-21-99
Residence: 5821 Hallowing Dr.	
Citizenship: UK	
Post Office Address: 5821 Hallowing Dr., Lorton, VA 22079	
Full name of joint inventor 3: Alberto Pique	
Inventor's signature:	DATE:
Recidence: Rowie MD 20715	